CM1248-04QG

EDS Protection Diode

Low Capacitance

Features

- Low I/O Capacitance at 10 pF at 0 V
- In-System ESD Protection to ±15 kV Contact Discharge, per the IEC 61000-4-2 International Standard
- Compact SMT Package Saves Board Space and Facilitates Layout in Space–Critical Applications
- Each I/O Pin Can Withstand over 1000 ESD Strikes
- These Devices are Pb-Free and are RoHS Compliant



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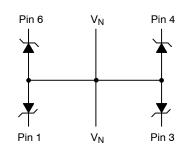
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UDFN-6 QG SUFFIX CASE 517BM

BLOCK DIAGRAM





MARKING DIAGRAM



LR = Specific Device Code

ORDERING INFORMATION

	Device	Package	Shipping [†]
(CM1248-04QG	uDFN-0.4 mm (Pb-Free)	3000/Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

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PACKAGE / PINOUT DIAGRAMS

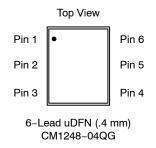


Table 1. PIN DESCRIPTIONS

Pins	Name	Description
(Refer to package / pinout diagrams)	CHx	The cathode of the respective surge protection diode, which should be connected to the node requiring transient voltage protection.
(Refer to package / pinout diagrams)	V _N	The anode of the surge protection diodes.

SPECIFICATIONS

Table 2. ABSOLUTE MAXIMUM RATINGS

Parameter	Rating	Units
Storage Temperature Range	–65 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Table 3. STANDARD OPERATING CONDITIONS

Parameter	Rating	Units
Operating Temperature	-40 to +85	°C

Table 4. ELECTRICAL OPERATING CHARACTERISTICS (Note 1)

Symbol	Parameter	Conditions	Min	Тур	Max	Units
C _{IN}	Channel Input Capacitance	T _A = 25°C, 0 VDC, 1 MHz; Note 2		10		pF
		0 VDC, 1 MHz; Note 1	7		15	pF
ΔC_{IN}	Differential Channel I/O to GND Capacitance	T _A = 25°C, 2.5 VDC, 1 MHz; Note 2		0.19		pF
V _{RSO}	Reverse Stand-off Voltage	I _R = 10 μA, T _A = 25°C	5.5			V
		I _R = 1 mA, T _A = 25°C	6.1			V
I _{LEAK}	Leakage Current	V_{IN} = 5.0 VDC, T_A = 25°C			0.25	μA
		V _{IN} = 5.0 VDC, Note 1			0.75	μA
V _{SIG}	Small Signal Clamp Voltage Positive Clamp Negative Clamp	I = 10 mA, T _A = 25°C I = –10 mA, T _A = 25°C		6.8 -0.89		V
V _{ESD}	ESD Withstand Voltage Contact Discharge per IEC 61000-4-2 standard	T _A = 25°C (Notes 2, 4 and 5)	±15			kV
R _D	Diode Dynamic Resistance Forward Conduction Reverse Conduction	T _A = 25°C (Notes 2 and 3)		0.57 1.36		Ω

1. All parameters specified at $T_A = -40^{\circ}C$ to $+85^{\circ}C$ unless otherwise noted.

All parameters specified at r_A = -40 C to +85 C timess otherwise noted.
These parameters guaranteed by design and characterization.
Human Body Model per MIL-STD-883, Method 3015, C_{Discharge} = 100 pF, R_{Discharge} = 1.5 KΩ, V_N grounded.
Standard IEC 61000-4-2 with C_{Discharge} = 150 pF, R_{Discharge} = 330 Ω, V_N grounded.
These measurements performed with no external capacitor on Pin_X.

CM1248-04QG

PERFORMANCE INFORMATION

Diode Capacitance

Typical diode capacitance with respect to positive cathode voltage (reverse voltage across the diode) is given in Diode Capacitance vs. Reverse Voltage.

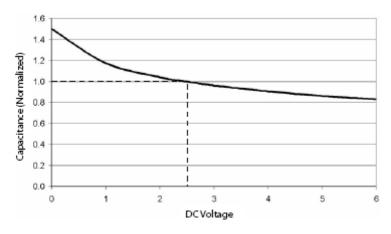


Figure 1. Diode Capacitance vs. Reverse Voltage

Typical High Current Diode Characteristics

Measurements are made in pulsed mode with a nominal pulse width of 0.7 ms.

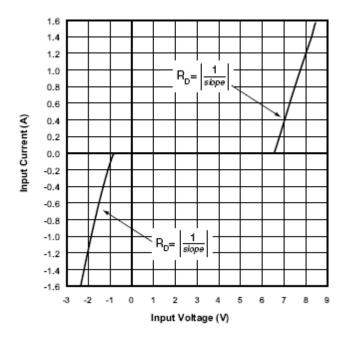
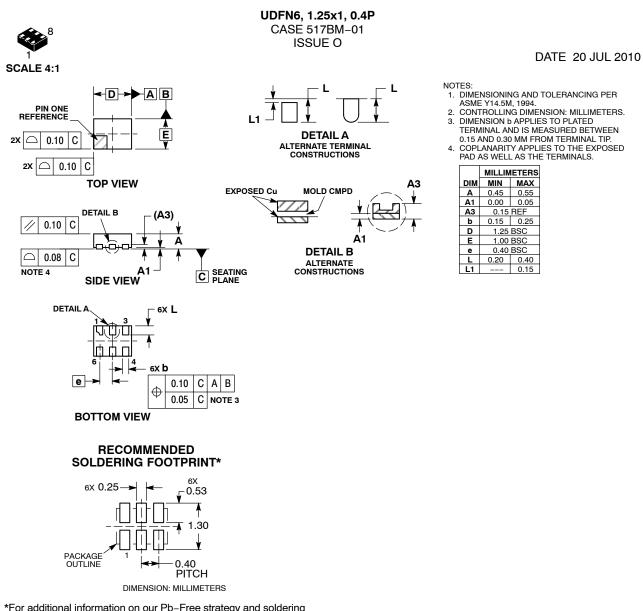


Figure 2. Typical Input VI Characteristics (Pulse-mode Measurements, Pulse Width = 0.7 ms nominal)





*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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